

### Features

- AEC Q100 Qualified
- 9A Peak Source/Sink Drive Current
- Wide Operating Voltage Range: 4.5V to 35V
- AEC Q100 Grade 1 -40°C to +125°C Operating Temperature Range
- Logic Input Withstands Negative Swing of up to 5V
- Matched Rise and Fall Times
- Low Propagation Delay Time
- Low, 10µA Supply Current
- Low Output Impedance

### Applications

- Automotive DC/DC Regulators
- Electronic Power Steering
- Electric Vehicle Power Train Drives
- Brushless DC Motors

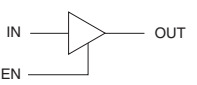
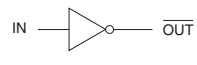
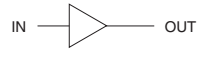


### Description

The IXD\_609SI is an automotive grade, high-speed gate driver that is qualified according to AEC Q100 standards. The IXD\_609SI output can source and sink 9A of peak current, while producing rise and fall times of less than 45ns. Both the output and input are rated to 35V. The input is virtually immune to latch-up, and proprietary circuitry eliminates cross conduction and "shoot-through." The IXD\_609SI has a Grade 1, -40°C to +125°C ambient operating temperature range.

The IXDD609SI is configured as a non-inverting driver with an enable, the IXDN609SI is configured as a non-inverting driver, and the IXDI609SI is configured as an inverting driver. The AEC Q100 qualified IXD\_609SI is available in an 8-pin Power SOIC package with an exposed metal back.

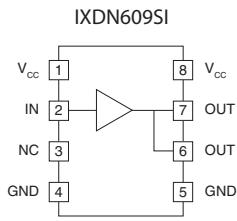
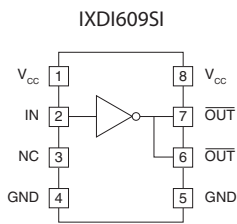
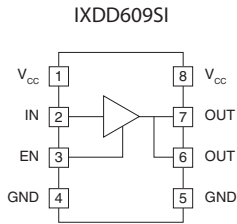
### Ordering Information

Part Number	Logic Configuration	Package Type	Packing Method	Quantity
IXDD609SI		8-Pin Power SOIC with Exposed Metal Back	Tube	100
IXDD609SITR			Tape & Reel	2000
IXDI609SI			Tube	100
IXDI609SITR			Tape & Reel	2000
IXDN609SI			Tube	100
IXDN609SITR			Tape & Reel	2000

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# 1 Specifications

## 1.1 Pin Configurations



## 1.2 Pin Definitions

Pin Name	Description
IN	Logic Input
EN	Output Enable - Drive pin low to disable output, and force output to a high impedance state
OUT	Output - Sources or sinks current to turn-on or turn-off a discrete MOSFET or IGBT
$\overline{\text{OUT}}$	Inverted Output - Sources or sinks current to turn-on or turn-off a discrete MOSFET or IGBT
V <sub>CC</sub>	Supply Voltage - Provides power to the device
GND	Ground - Common ground reference for the device
NC	Not connected

## 1.3 Absolute Maximum Ratings

Parameter	Symbol	Minimum	Maximum	Units
Supply Voltage	V <sub>CC</sub>	-0.3	40	V
Input Voltage	V <sub>IN</sub> , V <sub>EN</sub>	-5	V <sub>CC</sub> +0.3	V
Output Current	I <sub>OUT</sub>	-	±9	A
Junction Temperature	T <sub>J</sub>	-55	+150	°C
Storage Temperature	T <sub>STG</sub>	-65	+150	°C

Unless stated otherwise, absolute maximum electrical ratings are at 25°C

*Absolute maximum ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at conditions beyond those indicated in the operational sections of this data sheet is not implied.*

## 1.4 Recommended Operating Conditions

Parameter	Symbol	Range	Units
Supply Voltage	V <sub>CC</sub>	4.5 to 35	V
Operating Temperature Range	T <sub>A</sub>	-40 to +125	°C

**1.5 Electrical Characteristics:  $T_A = 25^\circ\text{C}$** 

 Test Conditions:  $4.5\text{V} \leq V_{CC} \leq 35\text{V}$  (unless otherwise noted).

Parameter	Conditions	Symbol	Minimum	Typical	Maximum	Units
Input Voltage, High	$4.5\text{V} \leq V_{CC} \leq 18\text{V}$	$V_{IH}$	3.0	-	-	V
Input Voltage, Low	$4.5\text{V} \leq V_{CC} \leq 18\text{V}$	$V_{IL}$	-	-	0.8	
Input Current	$0\text{V} \leq V_{IN} \leq V_{CC}$	$I_{IN}$	-	-	$\pm 10$	$\mu\text{A}$
EN Input Voltage, High	IXDD609SI only	$V_{ENH}$	$2/3V_{CC}$	-	-	V
EN Input Voltage, Low	IXDD609SI only	$V_{ENL}$	-	-	$1/3V_{CC}$	
Output Voltage, High	-	$V_{OH}$	$V_{CC}-0.025$	-	-	V
Output Voltage, Low	-	$V_{OL}$	-	-	0.025	
Output Resistance, High State	$V_{CC}=18\text{V}, I_{OUT}=-100\text{mA}$	$R_{OH}$	-	0.6	1	$\Omega$
Output Resistance, Low State	$V_{CC}=18\text{V}, I_{OUT}=100\text{mA}$	$R_{OL}$	-	0.4	0.8	
Output Current, Continuous	Limited by package power dissipation	$I_{DC}$	-	-	$\pm 2$	A
Rise Time	$V_{CC}=18\text{V}, C_{LOAD}=10\text{nF}$	$t_r$	-	22	35	ns
Fall Time	$V_{CC}=18\text{V}, C_{LOAD}=10\text{nF}$	$t_f$	-	15	25	
On-Time Propagation Delay	$V_{CC}=18\text{V}, C_{LOAD}=10\text{nF}$	$t_{ondly}$	-	40	60	
Off-Time Propagation Delay	$V_{CC}=18\text{V}, C_{LOAD}=10\text{nF}$	$t_{offdly}$	-	42	60	
Enable to Output-High Delay Time (IXDD609SI Only)	$V_{CC}=18\text{V}$	$t_{ENOH}$	-	25	60	
Disable to High Impedance State Delay Time (IXDD609SI Only)	$V_{CC}=18\text{V}$	$t_{DOLD}$	-	35	60	
Enable Pull-Up Resistor	-	$R_{EN}$	-	200	-	
Power Supply Current	$V_{CC}=18\text{V}, V_{IN}=3.5\text{V}$	$I_{CC}$	-	1	2	$\text{mA}$
	$V_{CC}=18\text{V}, V_{IN}=0\text{V}$		-	<1	10	
	$V_{CC}=18\text{V}, V_{IN}=V_{CC}$		-	<1	10	

**1.6 Electrical Characteristics:  $T_A = -40^\circ\text{C}$  to  $+125^\circ\text{C}$** 

 Test Conditions:  $4.5\text{V} \leq V_{CC} \leq 35\text{V}$  unless otherwise noted.

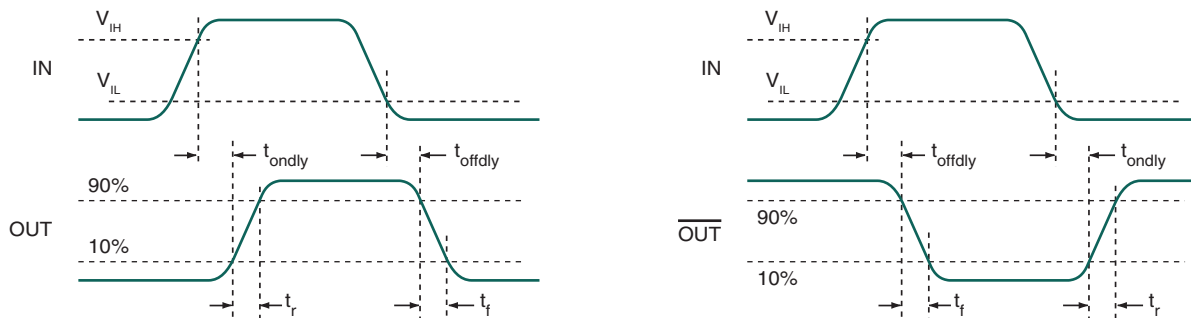
Parameter	Conditions	Symbol	Minimum	Maximum	Units
Input Voltage, High	$4.5\text{V} \leq V_{CC} \leq 18\text{V}$	$V_{IH}$	3.3	-	V
Input Voltage, Low	$4.5\text{V} \leq V_{CC} \leq 18\text{V}$	$V_{IL}$	-	0.65	
Input Current	$0\text{V} \leq V_{IN} \leq V_{CC}$	$I_{IN}$	-	$\pm 10$	$\mu\text{A}$
Output Voltage, High	-	$V_{OH}$	$V_{CC}-0.025$	-	V
Output Voltage, Low	-	$V_{OL}$	-	0.025	
Output Resistance, High State	$V_{CC}=18\text{V}, I_{OUT}=-100\text{mA}$	$R_{OH}$	-	2	$\Omega$
Output Resistance, Low State	$V_{CC}=18\text{V}, I_{OUT}=100\text{mA}$	$R_{OL}$	-	1.5	
Output Current, Continuous	Limited by package power dissipation	$I_{DC}$	-	$\pm 1$	A
Rise Time	$V_{CC}=18\text{V}, C_{LOAD}=10\text{nF}$	$t_r$	-	40	ns
Fall Time	$V_{CC}=18\text{V}, C_{LOAD}=10\text{nF}$	$t_f$	-	30	
On-Time Propagation Delay	$V_{CC}=18\text{V}, C_{LOAD}=10\text{nF}$	$t_{ondly}$	-	75	
Off-Time Propagation Delay	$V_{CC}=18\text{V}, C_{LOAD}=10\text{nF}$	$t_{offdly}$	-	75	
Enable to Output-High Delay Time	IXDD609SI only, $V_{CC}=18\text{V}$	$t_{ENOH}$	-	75	
Disable to High Impedance State Delay Time	IXDD609SI only, $V_{CC}=18\text{V}$	$t_{DOLD}$	-	75	
Power Supply Current	$V_{CC}=18\text{V}, V_{IN}=3.5\text{V}$	$I_{CC}$	-	2.5	
	$V_{CC}=18\text{V}, V_{IN}=0\text{V}$		-	150	
	$V_{CC}=18\text{V}, V_{IN}=V_{CC}$		-	150	$\mu\text{A}$

### 1.7 Thermal Characteristics

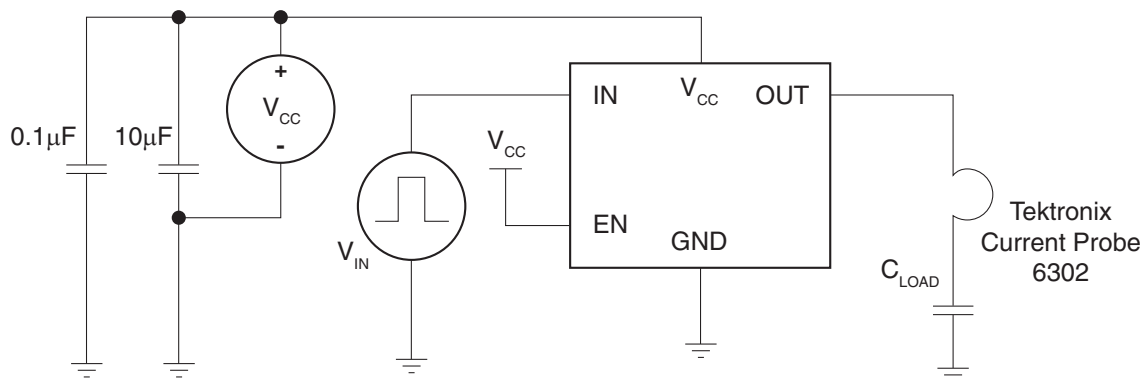
Package	Parameter	Symbol	Rating	Units
SI (8-Pin Power SOIC)	Thermal Resistance, Junction-to-Ambient	$\theta_{JA}$	85	°C/W
	Thermal Resistance, Junction-to-Case	$\theta_{JC}$	10	

## 2 IXD\_609SI Performance

### 2.1 Timing Diagrams

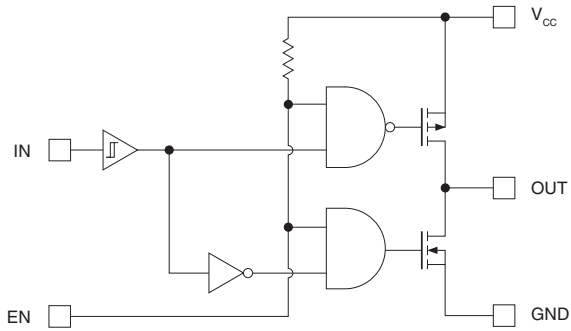


### 2.2 Characteristics Test Diagram



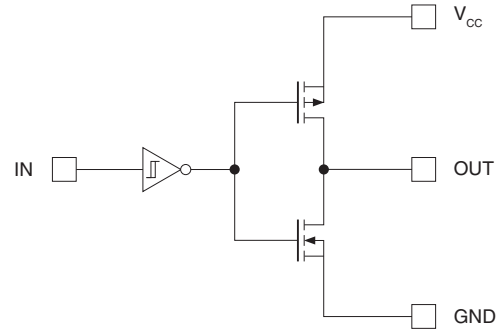
### 3 Block Diagrams & Truth Tables

#### 3.1 IXDD609SI



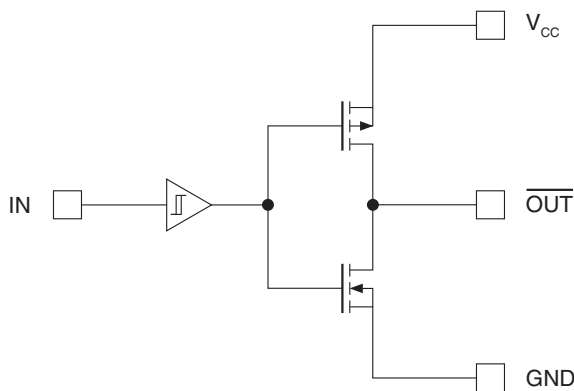
IN	EN	OUT
0	1 or open	0
1	1 or open	1
x	0	Z

#### 3.3 IXDN609SI



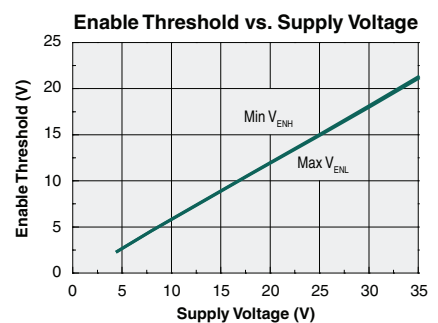
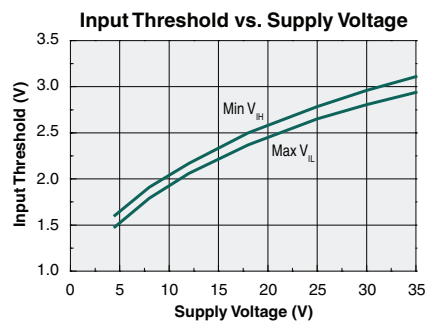
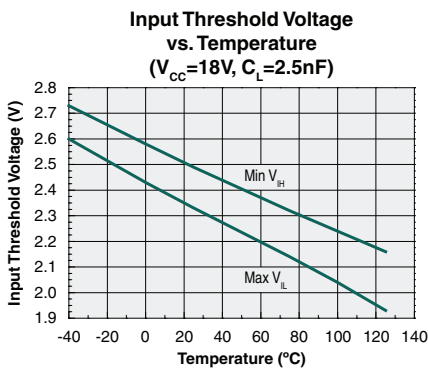
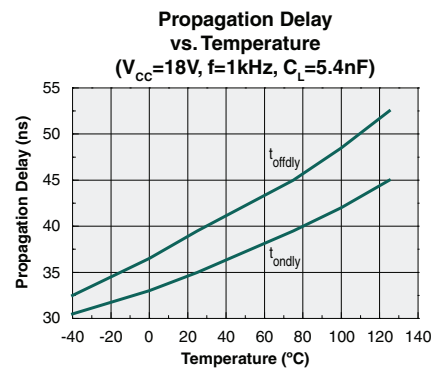
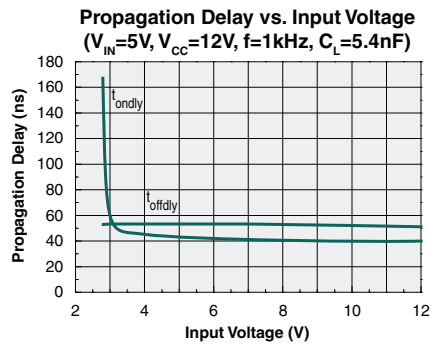
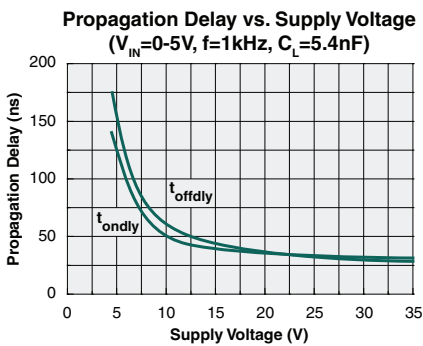
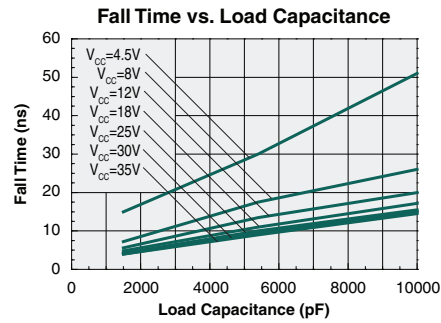
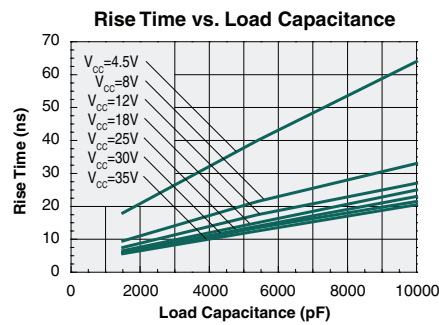
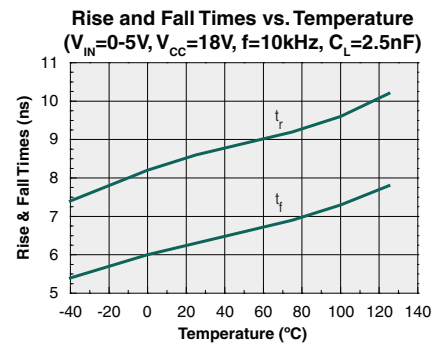
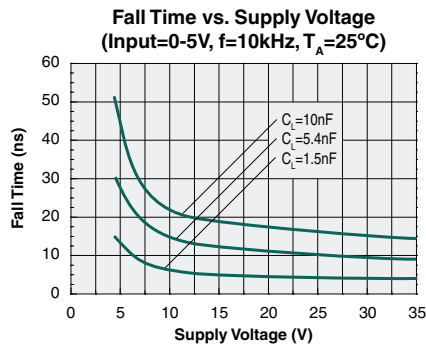
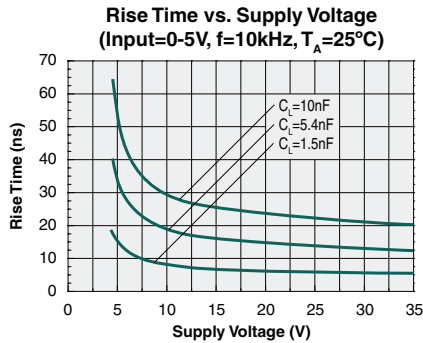
IN	OUT
0	0
1	1

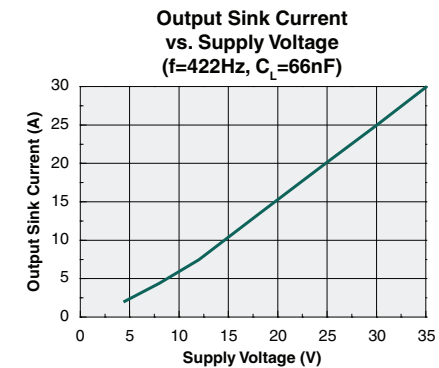
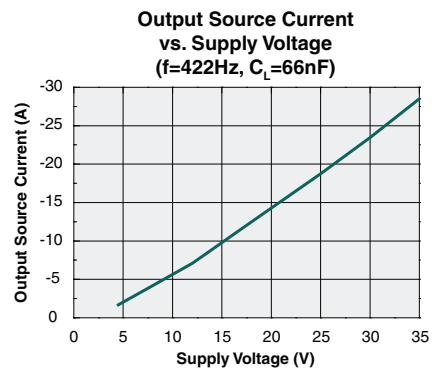
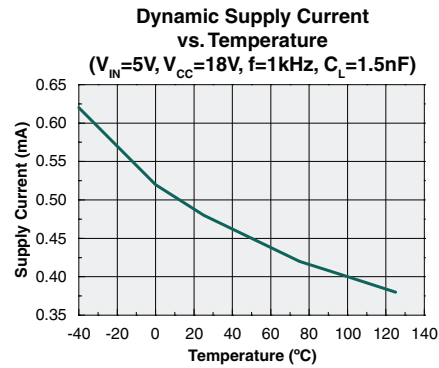
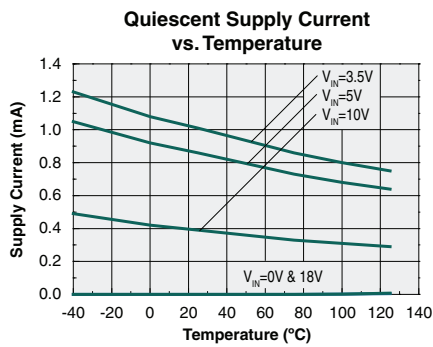
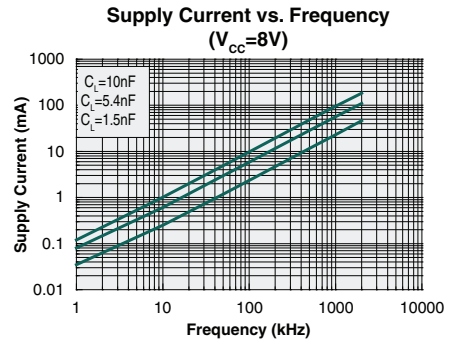
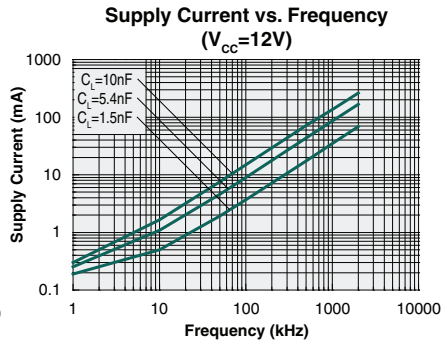
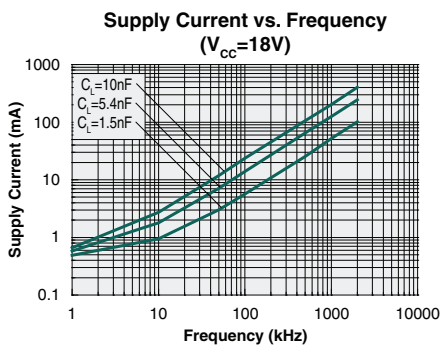
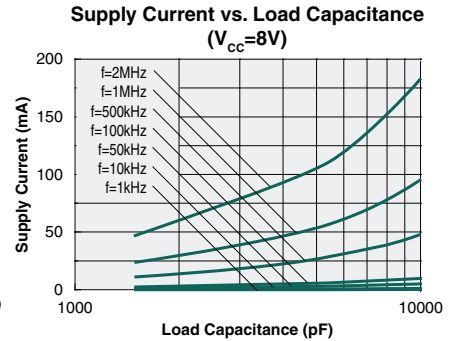
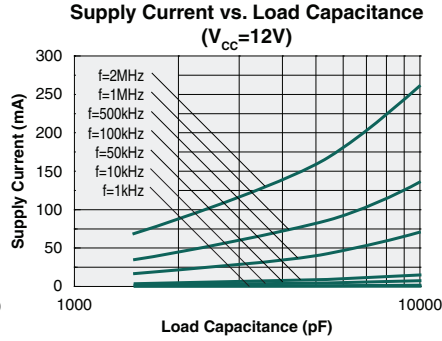
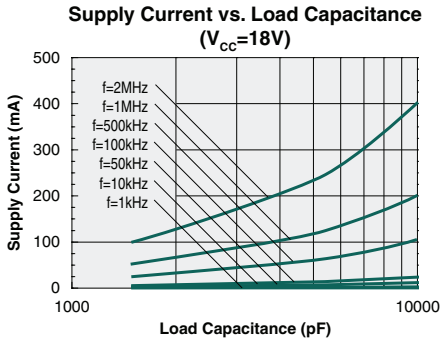
#### 3.2 IXDI609SI



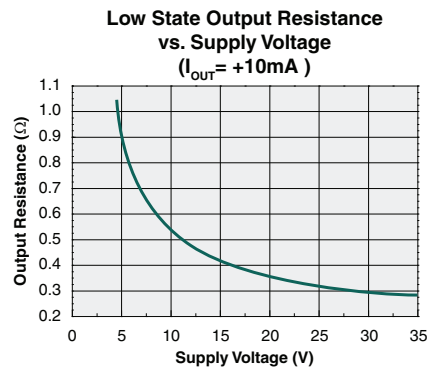
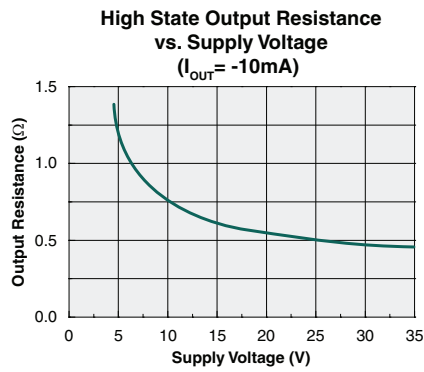
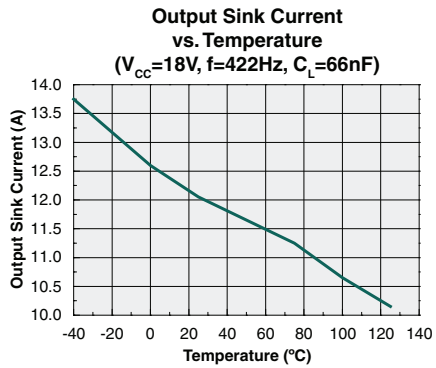
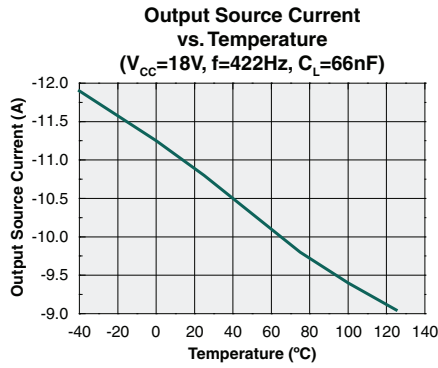
IN	OUT
0	1
1	0

## 4 Typical Performance Characteristics









## 5 Manufacturing Information

### 5.1 Moisture Sensitivity



All plastic encapsulated semiconductor packages are susceptible to moisture ingress. IXYS Integrated Circuits Division classified all of its plastic encapsulated devices for moisture sensitivity according to the latest version of the joint industry standard, **IPC/JEDEC J-STD-020**, in force at the time of product evaluation. We test all of our products to the maximum conditions set forth in the standard, and guarantee proper operation of our devices when handled according to the limitations and information in that standard as well as to any limitations set forth in the information or standards referenced below.

Failure to adhere to the warnings or limitations as established by the listed specifications could result in reduced product performance, reduction of operable life, and/or reduction of overall reliability.

This product carries a **Moisture Sensitivity Level (MSL) rating of 1**, and should be handled according to the requirements of the latest version of the joint industry standard **IPC/JEDEC J-STD-033**.

### 5.2 ESD Sensitivity



This product is **ESD Sensitive**, and should be handled according to the industry standard **JESD-625**.

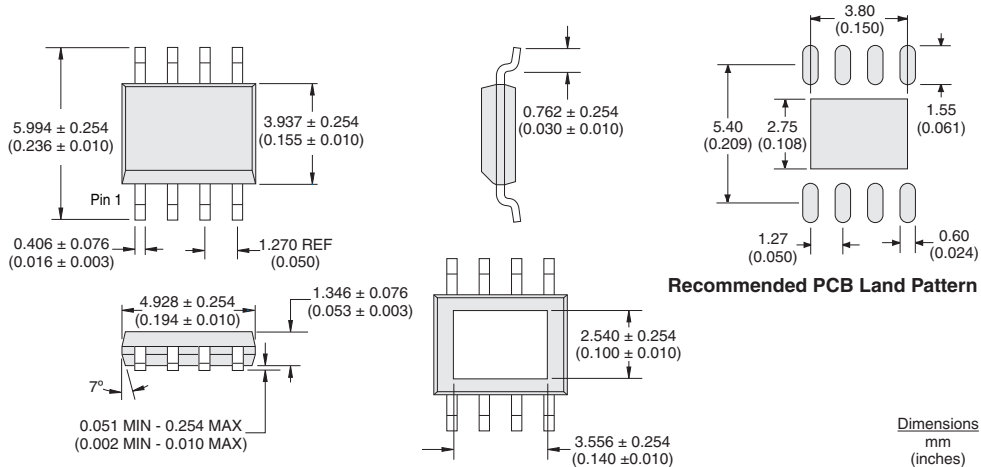
### 5.3 Reflow Profile

This product has a **maximum body temperature and time rating of 260°C for 30 seconds**. All other guidelines of **J-STD-020** must be observed.



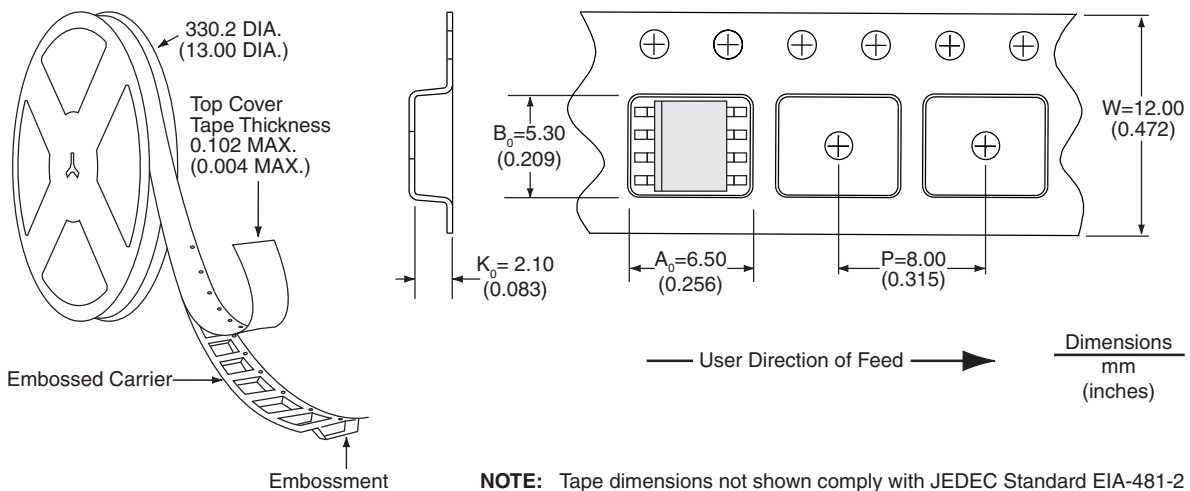
### 5.4 Mechanical Dimensions

#### 5.4.1 SI Package (8-Pin Power SOIC with Exposed Metal Back)



**Note:** The exposed metal pad on the back of the SI package should be connected to GND. It is not suitable for carrying current.

#### 5.4.2 Tape & Reel Information for SI Package



For additional information please visit our website at: [www.ixysic.com](http://www.ixysic.com)

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